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|  | <p>Hersteller-Teilenummer: SIHJ6N65E-T1-GE3</p> |
| | <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> |
|  | <p>Teil der Beschreibung: MOSFET N-CH 650V POWERPAK SO-8L</p> |
| | <p>Datenblätter:  SIHJ6N65E-T1-GE3.pdf</p> |
| <p>RoHs Status: Bleifrei / RoHS-konform</p> | <p>Lagerzustand: New original, Stock Available.</p> |
| <p>Lieferung von: Hong Kong</p> | <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |






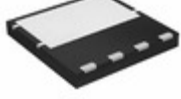


Spezifikationen

| | |
|--------------------------------------------------|--------------------------------------------------|
| Teilenummer | SIHJ6N65E-T1-GE3 |
| Hersteller | Electro-Films (EFI) / Vishay |
| Beschreibung | MOSFET N-CH 650V POWERPAK SO-8L |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | Require For Quote & Check Stock |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Vgs (Max) | ±30V |
| Technologie | MOSFET (Metal Oxide) |
| Supplier Device-Gehäuse | PowerPAK® SO-8 |
| Serie | - |
| Rds On (Max) @ Id, Vgs | 868 mOhm @ 3A, 10V |
| Verlustleistung (max) | 74W (Tc) |
| Verpackung | Tape & Reel (TR) |
| Verpackung / Gehäuse | PowerPAK® SO-8 |
| Andere Namen | SIHJ6N65E-T1-GE3TR |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Eingabekapazität (Ciss) (Max) @ Vds | 596pF @ 100V |
| Gate Charge (Qg) (Max) @ Vgs | 32nC @ 10V |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Drain-Source-Spannung (Vdss) | 650V |
| detaillierte Beschreibung | N-Channel 650V 5.6A (Tc) 74W (Tc) Surface Mount |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 5.6A (Tc) |

SIHJ6N65E-T1-GE3 Electronic Components ist ein 100% neues Original von YIC Distributor, SIHJ6N65E-T1-GE3-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, SIHJ6N65E-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.

RFQ SIHJ6N65E-T1-GE3 E-Mail: Info@Y-IC.com

Sie können auch interessiert

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|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <p>sein:</p>  <p>SIHJ8N60E-T1-GE3 Vishay Siliconix MOSFET N-CH 600V POWERPAK SO-8L</p> |  <p>SIHJ240N60E-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 600V PPAK SO-8L</p> |  <p>SIHJ8N60E-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V POWERPAK SO-8L</p> |  <p>SIHJ7N65E-T1-GE3 Vishay Siliconix MOSFET N-CH 650V POWERPAK SO-8L</p> |
|  <p>SIHH28N60E-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 29A POWERPAK8</p> |  <p>SIHH28N60E-T1-GE3 Vishay Siliconix MOSFET N-CH 600V 29A 8-PWRTDFN</p> |  <p>SIHJ10N60E-T1-GE3 Vishay Siliconix MOSFET N-CH 600V 10A SO8</p> |  <p>SIHJ6N65E-T1-GE3 Vishay Siliconix MOSFET N-CH 650V POWERPAK SO-8L</p> |

Verwandtes Hot-Keyword

Mehr

| | | | | |
|-----------------------------------------------|------------------------------|-------------------------------|------------------------|-----------------------------------|
| SIHJ6N65E-T1-GE3 Electro-Films (EFI) / Vishay | SIHJ6N65E-T1-GE3 Datenblatt | SIHJ6N65E-T1-GE3-Datenblätter | SIHJ6N65E-T1-GE3 PDF | Electro-Films (EFI) / Vishay |
| SIHJ6N65E-T1-GE3 Electronic | SIHJ6N65E-T1-GE3-Komponenten | SIHJ6N65E-T1-GE3-Verteiler | SIHJ6N65E-T1-GE3-Bild | SIHJ6N65E-T1-GE3-Teil |
| SIHJ6N65E-T1-GE3 Preis | SIHJ6N65E-T1-GE3 Hersteller | SIHJ6N65E-T1-GE3 Bild | SIHJ6N65E-T1-GE3 Aktie | SIHJ6N65E-T1-GE3 Inventar |
| SIHJ6N65E-T1-GE3 Neu | SIHJ6N65E-T1-GE3 Original | SIHJ6N65E-T1-GE3 garantiert | SIHJ6N65E-T1-GE3 RFQ | SIHJ6N65E-T1-GE3 Online bestellen |

Contact us: **Info@Y-IC.com**

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